



ON Semiconductor®

<http://onsemi.com>

LV0221CS

CMOS IC

Front Monitor OE-IC for Optical Pickups

Overview

The LV0221CS is a front monitor optoelectronic IC for optical pickups that has a built-in photo diode compatible with three waveforms. LV0221CS is small size and type CSP packages.

Functions

- PIN photodiode compatible with three wavelengths incorporated.
- Gain adjustment (-6dB to +6dB in 256 steps) through serial communication.
- Amplifier to amplify differential output.

Specifications

Maximum Ratings at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings	Unit
Maximum supply voltage	V_{CC}		6	V
Allowable power dissipation	Pd1	Glass epoxy one-side substrate 55mm × 45mm × 0.8mm Copper foil area (about 80%), $T_a = 75^\circ\text{C}$	136	mW
	Pd2	Glass epoxy one-side substrate 55mm × 45mm × 0.8mm Copper foil area (head: about 85% Tail: about 90%), $T_a = 75^\circ\text{C}$	100	mW
Operating temperature	T_{opr}		-20 to +85	$^\circ\text{C}$
Storage temperature	T_{stg}		-40 to +100	$^\circ\text{C}$

Stresses exceeding Maximum Ratings may damage the device. Maximum Ratings are stress ratings only. Functional operation above the Recommended Operating Conditions is not implied. Extended exposure to stresses above the Recommended Operating Conditions may affect device reliability.

Recommended Operating Conditions at $T_a = 25^\circ\text{C}$

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Operating supply voltage	V_{CC}		4.5	5	5.5	V
Output load capacitance	C_O		12	20	33	pF
Output load resistance	Z_O		3			k Ω

LV0221CS

Electrical Characteristics at Ta = 25°C, VCC = 5V, RL=6kΩ, CL=20pF

Parameter	Symbol	Conditions	Ratings			Unit
			min	typ	max	
Current dissipation	ICC			18	23.4	mA
Sleep current	Islp				1	mA
Output voltage when shielded	VC	At shielding	1.8	2.0	2.2	V
Output offset voltage	Vofs	At shielding, voltage between VOP-VON	-30	0	30	mV
Temperature dependence of offset voltage *1	Vofs	Ta=-10 to +85°C	-60	0	60	μV/°C
Optical output voltage *1 Voltage between VOP-VON	VLC	Low Gain, λ=780nm, G=0dB	0.21	0.262	0.31	mV/μW
	VLD	Low Gain, λ=650nm, G=0dB	0.22	0.275	0.33	mV/μW
	VLB	Low Gain, λ=405nm, G=0dB	0.14	0.172	0.21	mV/μW
	VMC	Middle Gain, λ=780nm, G=0dB	0.66	0.83	0.99	mV/μW
	VMD	Middle Gain, λ=650nm, G=0dB	0.70	0.87	1.05	mV/μW
	VMB	Middle Gain, λ=405nm, G=0dB	0.43	0.54	0.65	mV/μW
	VHC	High Gain, λ=780nm, G=0dB	1.97	2.46	2.95	mV/μW
	VHD	High Gain, λ=650nm, G=0dB	2.07	2.58	3.10	mV/μW
	VHB	High Gain, λ=405nm, G=0dB	1.29	1.62	1.94	mV/μW
Light output voltage adjustment range *1	G	G=0dB reference, absolute value of adjustment width	5.5	6.0	6.5	dB
D range *1	VoD	Voltage between VOP-VON	1700	2200		mV
Frequency characteristics *1, *2	FcC	-3dB(1MHz reference), λ=780nm Light input = 40μW(DC) + 20μW(AC)	50	75		MHz
	FcD	-3dB(1MHz reference), λ=650nm Light input = 40μW(DC) + 20μW(AC)	60	85		MHz
	FcB	-3dB(1MHz reference), λ=405nm Light input = 40μW(DC) + 20μW(AC)	60	85		MHz
Settling time *1	Tset			15		ns
Response time *1	Tr, Tf	Vo=0.9Vp-p, output level 10 to 90% fc=10MHz, duty=50%			10	ns
Overshoot *1	Ovst	Vo=0.9Vp-p			15	%
Undershoot *1	Unst	Vo=0.9Vp-p			15	%
Linearity *1	Lin	At output voltage 0.5V and 1.0V (Between VOP-VON)	-1	0	1	%
Light-output voltage temperature dependence Voltage between VOP-VON *1, *3	TC	λ=780nm, 25°C reference	10	13	16	%
	TD	λ=650nm, 25°C reference	0	3	6	%
	TB	λ=405nm, 25°C reference	0	3	6	%
Light-output voltage spectral sensitivity Voltage between VOP-VON *1	Vf	λ=785nm ±10nm	-0.8		0.1	%/nm
		λ=660nm ±10nm	-0.4		0.4	%/nm
		λ=405nm ±10nm	0		1.2	%/nm
Step-step voltage ratio *1	DG	(Vn-Vn-1) / Vn *100 *4 Deviation from the ideal curve of above equation	-3	0	3	%

Item with *1 mark indicate the design reference value.

Item with *2 mark indicate the frequency characteristics when VOP and VON are applied individually.

The frequency characteristics are for the case of High / Middle / Low gain and for the case when the output voltage adjustment range is -6 to +6dB

Item with *3 mark indicates the temperature dependence for the case of High / Middle / Low gain and for the case when the temperature is 25 to 85°C for the output voltage adjustment range of -6 to +6dB

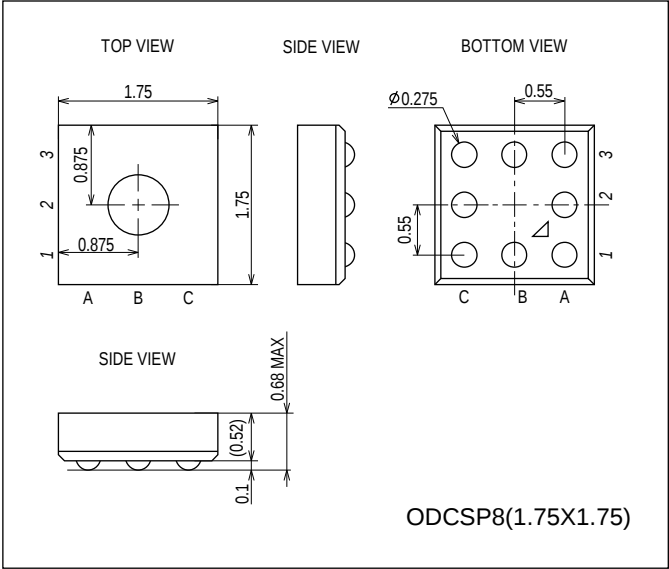
Vn in Item with *4 mark is $Vn = (\text{sensitivity} / 2) \times 5400 / (5400 - 16 \times \text{GCAstep}) \times \text{light intensity} (\mu\text{W})$

GCA = Gain Control Amplifier

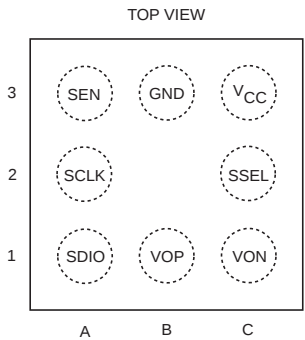
Package Dimensions

unit : mm (typ)

3402

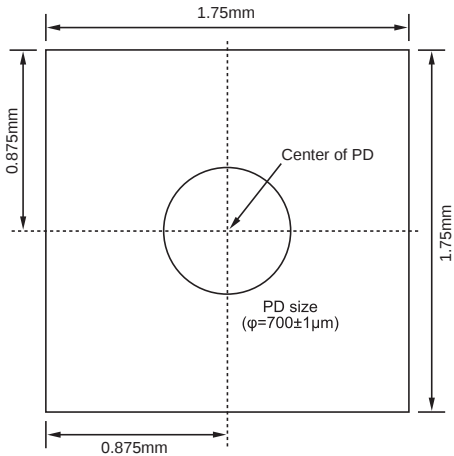


Pin Assignment



Pin No.	Pin name	Function
1A	SDIO	Serial communication Data pin
1B	VOP	Positive side output pin
1C	VON	Negative side output pin
2A	SCLK	Serial communication Clock pin
2C	SSEL	Register selection pin SSEL = Low, Open : Address 00 to 0Fh used SSEL = High : Address 10 to 1Fh used
3A	SEN	Serial communication Enable pin
3B	GND	GND pin
3C	VCC	Power supply voltage pin

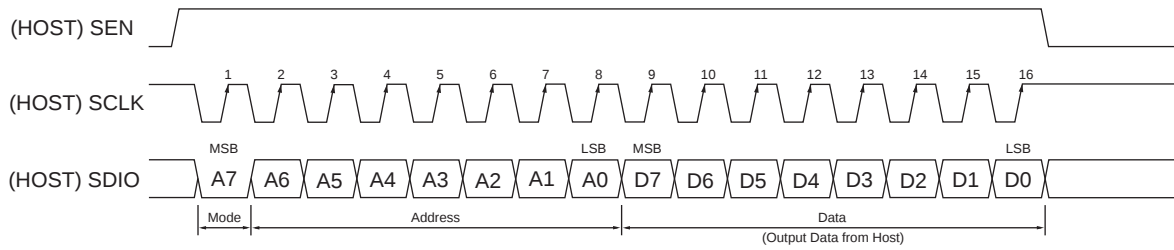
PD assignment



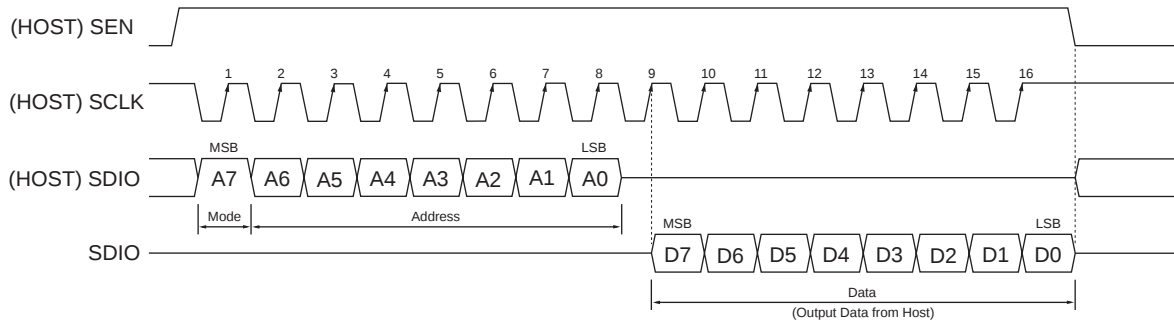
*PD size for reference to be used for design

Serial protocol

WRITE timing chart

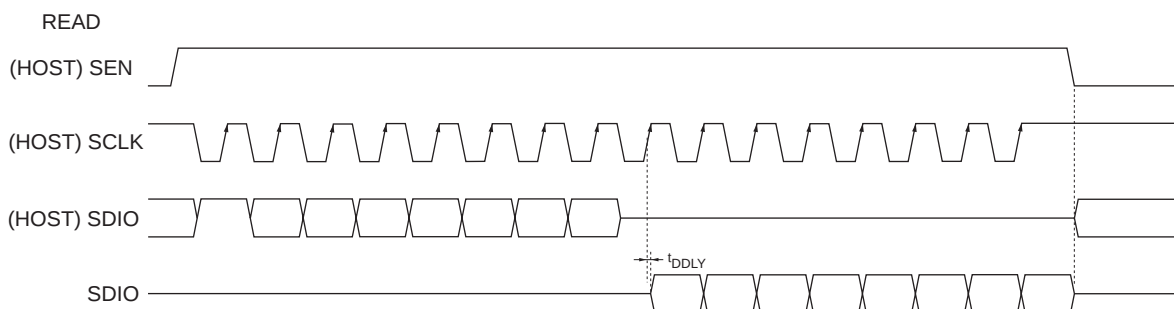
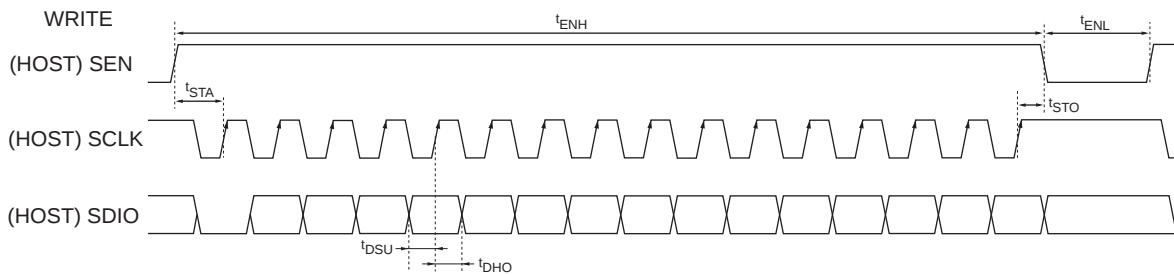


READ timing chart



SDIO pin load / CL=20pF (The table below shows the design reference value.)

Parameter	Symbol	Min.	Typ.	Max.	Unit
SCL clock frequency Write	f_{SCL}	0		10	MHz
SCL clock frequency Read	f_{SCL}	0		4	MHz
SDIO data setup time	t_{DSU}	50			ns
SDIO data hold time	t_{DHO}	50			ns
SDIO output delay	$t_{DDL Y}$		10	80	ns
SEN "H" period	t_{ENH}	1.6			μ s
SEN "L" period	t_{ENL}	200			ns
SCL rise time after SEN rise	t_{STA}	60			ns
SEN fall time after final SCL rise	t_{STO}	100			ns
Serial input "H" voltage	V_{IH}	2.4			V
Serial input "L" voltage	V_{IL}			0.6	V
SDIO output "H" voltage	V_{OH}	2.5	2.9	3.3	V
SDIO output "L" voltage	V_{OL}	0	0.3	0.8	V



LV0221CS

Pin	Type	Equivalent circuit diagram
SDIO	Input Output	
VOP VON	Output	
SCLK SSEL SEN	Input	

ON Semiconductor and the ON logo are registered trademarks of Semiconductor Components Industries, LLC (SCILLC). SCILLC owns the rights to a number of patents, trademarks, copyrights, trade secrets, and other intellectual property. A listing of SCILLC's product/patent coverage may be accessed at www.onsemi.com/site/pdf/Patent-Marking.pdf. SCILLC reserves the right to make changes without further notice to any products herein. SCILLC makes no warranty, representation or guarantee regarding the suitability of its products for any particular purpose, nor does SCILLC assume any liability arising out of the application or use of any product or circuit, and specifically disclaims any and all liability, including without limitation special, consequential or incidental damages. "Typical" parameters which may be provided in SCILLC data sheets and/or specifications can and do vary in different applications and actual performance may vary over time. All operating parameters, including "Typicals" must be validated for each customer application by customer's technical experts. SCILLC does not convey any license under its patent rights nor the rights of others. SCILLC products are not designed, intended, or authorized for use as components in systems intended for surgical implant into the body, or other applications intended to support or sustain life, or for any other application in which the failure of the SCILLC product could create a situation where personal injury or death may occur. Should Buyer purchase or use SCILLC products for any such unintended or unauthorized application, Buyer shall indemnify and hold SCILLC and its officers, employees, subsidiaries, affiliates, and distributors harmless against all claims, costs, damages, and expenses, and reasonable attorney fees arising out of, directly or indirectly, any claim of personal injury or death associated with such unintended or unauthorized use, even if such claim alleges that SCILLC was negligent regarding the design or manufacture of the part. SCILLC is an Equal Opportunity/Affirmative Action Employer. This literature is subject to all applicable copyright laws and is not for resale in any manner.